# Tailoring multifunctional anion to inhibit methanol absorption in CsPbBr<sub>3</sub> quantum dot surface for highly efficient semitransparent photovoltaics

Yinyan Xu,<sup>a</sup> Pujun Niu,<sup>a</sup> Lun Zhang,<sup>a</sup> Ziyin Wen,<sup>a</sup> Sheng Cheng<sup>b</sup>, Mei Lyu,<sup>a</sup> and Jun Zhu\*<sup>a</sup>

a. Special Display and Imaging Technology Innovation Center of Anhui Province, Anhui Province Key Laboratory of Measuring Theory and Precision Instrument, Anhui Province Key Laboratory of Advance Functional Materials and Devices, Academy of Opto-Electric Technology, Hefei University of Technology, Hefei 230009, China.

b. Instrumental Analysis Center, Hefei University of Technology, Hefei 230009, China \*E-mail: jzhu@hfut.edu.cn

### **Experimental section**

Chemicals

All reagents were used as received without further purification. Octadecene (ODE, 90%), oleic acid (OA, 90%), methyl acetate (MeOAc, 99%), chlorobenzene (CB 99.9%) guanidine bromide (GuaBr, 99.5%), guanidinium thiocyanate (GuaSCN, 99.8%), guanidine acetate (GuaAc, 99.5%) were obtained from Sigma-Aldrich., oleylamine (OAm, 90%), and octane (98%) were obtained from Alfa Aesar. PbI<sub>2</sub> (99.99%) and PCBM (99.9%) were obtained from Xi'an Polymer Light Technology Corp. Cs<sub>2</sub>CO<sub>3</sub> (99.9%) was obtained from J&K. Spiro-OMeTAD (99.8%) was obtained from Ningbo Borun New Material Co., Ltd. n-hexane (97%), TiCl<sub>4</sub> (98%), and ethyl alcohol ( $\geq$ 99.7%) were purchased from Sinopharm Chemical Reagent Co., Ltd.

## Synthesis of CsPbBr<sub>3</sub> QDs

The synthesis of CsPbBr<sub>3</sub> QDs employed here followed the previously published method. Cesium oleate was prepared by adding ODE (25 mL), Cs<sub>2</sub>CO<sub>3</sub> (0.25 g), OA (1 mL) into a 50 mL three-neck flask. It was degassed and dried under vacuum for 30

min at 120 °C until a clear solution was obtained.

For the synthesis of CsPbBr<sub>3</sub> QDs, PbBr<sub>2</sub> (0.4 g), and ODE (25 mL) were loaded into a 50 mL 3-neck flask and heated to 120 °C under vacuum for 30 min, then OA (2.5 mL), OAm (2.5 mL) were injected into the system under the protection of N<sub>2</sub>. The flask was put under vacuum again (30 min). The temperature was increased to 170 °C and Cs-oleate solution (4 mL) was quickly injected. After 5 s the solution was immediately cooled down to room temperature by immersing the flask in an ice water bath. The synthesized CsPbBr<sub>3</sub> QDs were precipitated by adding 24 ml of MeOAc to 8 ml of the QD reaction liquor (volume ratio of QD reaction solution: MeOAc is 1:3) and then centrifuged at 8500 rpm for 3 min. The wet pellet of QDs in each centrifuge tube was redispersed in 5 mL hexane, precipitated again with 15 mL MeOAc and centrifuged at 8500 rpm for 3 min. The resultant QD pellet was dispersed in 10 ml of hexane and then stored in the dark at 4 °C for at least 24 hours to precipitate excess Cs-oleate and Pb-oleate. Before use, these solid precipitates were removed from the QD solution via centrifugation at 8000 rpm for 3 min.

### Fabrication of solar cells

FTO glass is cleaned with deionized water, ethanol, and isopropanol. TiO<sub>2</sub> electron transport layer is prepared by the chemical bath deposition method. Before depositing CsPbBr<sub>3</sub> QDs, the FTO/TiO<sub>2</sub> substrates were treated by UV-zone for about 20 min and transferred to a glove box which a relatively-controlled humidity condition from 15% to 20% for efficient ligand exchange. For the fabrication of CsPbBr<sub>3</sub> QD films based on solid state ligand exchange, CsPbBr<sub>3</sub> QD solution in octane (85 mg/mL) was spin-coated onto the c-TiO<sub>2</sub>/FTO substrates at 1000 rpm for 20 s followed by 2500 rpm for 5 s. The as-cast CsPbBr<sub>3</sub> QD film was soaked in the ligand solution (the respective ionic salts (GuaBr, GuaSCN, GuaAc) in MeOAc) and spin-dried. And then, the ligand-treated film was washed using neat MeOAc and spin-dried. This process needed to repeat five times to obtain thick enough CsPbBr<sub>3</sub> QD film. The as-prepared substrate was transferred to a glove box with pure N<sub>2</sub> to deposit the hole transfer layer. Spiro-MeOTAD used as an HTL in solar cells was spin-coated at 4000 rpm for 30 s.

The spiro-MeOTAD solution was prepared as follows: spiro-MeOTAD (72.3 mg), chlorobenzene (1 mL), 4-tert-butylpyridine (28.8  $\mu$ L) and Li-TFSI (17.5  $\mu$ L) solution in acetonitrile with the concentration of 520 mg/mL. In the end, Au electrode (80 nm) was fabricated by thermal evaporation.

## Characterization

The transmission electron microscope (TEM) images of CsPbI<sub>3</sub> QDs were obtained by JEM-2100F. The optical properties of the samples were measured by an UV–vis spectrophotometer (UV-2550). The steady-state PL and PLQY were obtained by HoribaFluoroMax-4 fluorescence spectrometer. XRD patterns of perovskite films and QDs were measured using PANalytical X-Rert PRO MPD. Top-view surface morphology of films was performed using Gemini 500. XPS spectra were recorded using an X-ray photoelectron spectrometer (Thermo Scientific ESCALAB 250Xi). AFM topography images were acquired on a Bruker Dimension Icon instrument. The photocurrent density-voltage (J-V) characteristics of solar cells were measured under AM 1.5G illumination at 100 mW/cm<sup>2</sup> (Newport Sol3A solar simulators) using a Keithley 2450 source meter.



Figure S1. a) TEM image of purified CsPbBr<sub>3</sub> QDs with an average size around 10 nm. b) The

corresponding particle size distributions



Figure S2. UV-vis absorption and PL spectra of CsPbBr<sub>3</sub> QD solution in hexane.



Figure S3. CsPbBr3 QD solid fabrication using solid-state ligand exchange based on layer-by-

layer process.



Figure S4. XRD patterns of CsPbBr3 QD films with and without GuaBr, GuaSCN and GuaBr

treatment.



Figure S5. XPS (a) Cs 1s, (b) Pb 4f, (c) Br 3d and (d) C 1s of CsPbBr<sub>3</sub> QD films with and without GuaBr, GuaSCN, GuaAc treatment.



Figure S6. a) The top-view SEM, b) AFM height images of CsPbBr<sub>3</sub> QD films with and without

GuaBr, GuaSCN and GuaAc treatment.



**Figure S7.** *J-V* characteristic curve of CsPbBr<sub>3</sub> QD solar cells treated with different concentrations of GuaBr in MeOAc (0, 0.25, 0.5, 0.75, 1 mg/mL).



**Figure S8**. *J-V* characteristic curve of CsPbBr<sub>3</sub> QD solar cells treated with different concentrations of GuaSCN in MeOAc (0, 0.25, 0.5, 0.75, 1 mg/mL).



**Figure S9**. *J-V* characteristic curve of CsPbBr<sub>3</sub> QD solar cells treated with different concentrations of GuaAc in MeOAc (0, 0.25, 0.5, 0.75, 1 mg/mL).



Figure S10. Statistics on photovoltaic parameters of  $V_{OC}$ ,  $J_{SC}$ , FF, and PCE of CsPbBr<sub>3</sub> QD solar cell with and without GuaBr, GuaSCN, GuaAc treatment.



Figure S11. J-V curves of CsPbBr3 solar cells with and without GuaAc treatment under reverse

and forward scan.



Figure S12. J-V curves of CsPbBr $_3$  QD solar cells based on acetone and acetone + GuaAc

treatment.

Sample	Voc	$J_{\rm sc}$	FF	PCE <sub>max</sub>
	<b>(V)</b>	(mA/cm <sup>2</sup> )	(%)	(%)
0 mg/mL	1.57	4.48	64.4	4.52
0.25mg/mL	1.58	4.68	65.3	4.83
0.5 mg/mL	1.58	4.91	70.6	5.48
0.75 mg/mL	1.56	4.61	69.0	5.02
1 mg/mL	1.54	4.16	64.1	4.12

**Table S1** Photovoltaic parameters of CsPbBr<sub>3</sub> QD solar cells treated with different concentrations of GuaBr.

**Table S2** Photovoltaic parameters of CsPbBr<sub>3</sub> QD solar cells treated with different concentrations of GuaSCN.

Sample	V <sub>oc</sub>	J <sub>sc</sub>	FF	PCE <sub>max</sub>
	<b>(V)</b>	(mA/cm <sup>2</sup> )	(%)	(%)
0 mg/mL	1.55	5.08	61.2	4.83
0.25mg/mL	1.56	5.35	61.2	5.11
0.5 mg/mL	1.57	5.62	62.0	5.48
0.75 mg/mL	1.58	5.93	61.8	5.88
1 mg/mL	1.57	5.15	65.8	5.34

 Table S3 Photovoltaic parameters of CsPbBr<sub>3</sub> QD solar cells treated with different concentrations

 of GuaAc.

Sample	Voc	J <sub>sc</sub>	FF	PCE <sub>max</sub>
	<b>(V)</b>	(mA/cm <sup>2</sup> )	(%)	(%)
0 mg/mL	1.58	4.60	69.0	5.02
0.25mg/mL	1.58	5.27	69.1	5.76
0.5 mg/mL	1.59	5.69	72.9	6.61
0.75 mg/mL	1.58	5.41	70.8	6.07
1 mg/mL	1.59	5.62	62.8	5.61

Sample	V <sub>oc</sub>	$J_{\rm sc}$	FF	PCE <sub>max</sub>
	(V)	(mA/cm <sup>2</sup> )	(%)	(%)
Control	1.58	4.60	69.0	5.02
GuaBr	1.57	5.18	71.1	5.82
GuaSCN	1.58	5.23	72.9	6.03
GuaAc	1.59	5.93	74.7	7.04

Table S4 Photovoltaic parameters of  $CsPbBr_3$  QD solar cells with and without GuaBr, GuaSCN and GuaAc treatment